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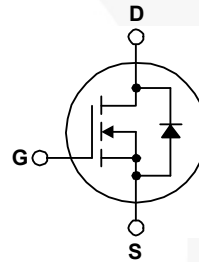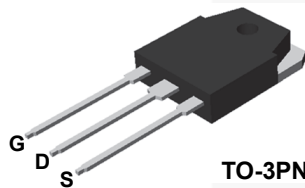
FQA140N10

N-Channel QFET® MOSFET

100 V, 140 A, 10 mΩ

June 2014

Description

This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, audio amplifier, DC motor control, and variable switching power applications.

Features

- 140 A, 100 V, $R_{DS(on)}$ = 10 mΩ (Max.) @ V_{GS} = 10 V, I_D = 70 A

- Low Gate Charge (Typ. 220 nC)

- Low Crss (Typ. 470 pF)

- 100% Avalanche Tested

- 175°C Maximum Junction Temperature Rating

TO-3PN

Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol	Parameter		FQA140N10	Unit
V_{DSS}	Drain-Source Voltage		100	V
I_D	Drain Current — Continuous (T_C = 25°C)		140	A
	— Continuous (T_C = 100°C)		99	A
I_{DM}	Drain Current — Pulsed	(Note 1)	560	A
V_{GSS}	Gate-Source Voltage		± 25	V
E_{AS}	Single Pulsed Avalanche Energy	(Note 2)	1500	mJ
I_{AR}	Avalanche Current	(Note 1)	140	A
E_{AR}	Repetitive Avalanche Energy	(Note 1)	37.5	mJ
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	6.5	V/ns
P_D	Power Dissipation (T_C = 25°C)		375	W
	— Derate above 25°C		2.5	W/°C
T_J, T_{STG}	Operating and Storage Temperature Range		-55 to +175	°C
T_L	Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds.		300	°C

Thermal Characteristics

Symbol	Parameter	FQA140N10	Unit
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	0.4	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient, Max.	40	°C/W

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Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FQA140N10	FQA140N10	TO-3PN	Tube	N/A	N/A	30 units

Electrical Characteristics T_C = 25°C unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
Off Characteristics						
BV_{DSS}	Drain-Source Breakdown Voltage	V_{GS} = 0 V, I_D = 250 μA	100	--	--	V
ΔBV_{DSS} / ΔT_J	Breakdown Voltage Temperature Coefficient	I_D = 250 μA, Referenced to 25°C	--	0.08	--	V/°C
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS} = 80 V, V_{GS} = 0 V	--	--	1	μA
		V_{DS} = 64 V, T_C = 150°C	--	--	10	μA
I_{GSSF}	Gate-Body Leakage Current, Forward	V_{GS} = 25 V, V_{DS} = 0 V	--	--	100	nA
I_{GSSR}	Gate-Body Leakage Current, Reverse	V_{GS} = -25 V, V_{DS} = 0 V	--	--	-100	nA
On Characteristics						
$V_{GS(th)}$	Gate Threshold Voltage	V_{DS} = V_{GS}, I_D = 250 μA	2.0	--	4.0	V
$R_{DS(on)}$	Static Drain-Source On-Resistance	V_{GS} = 10 V, I_D = 70 A	--	0.008	0.01	Ω
g_{FS}	Forward Transconductance	V_{DS} = 30 V, I_D = 70 A	--	80	--	S
Dynamic Characteristics						
C_{iss}	Input Capacitance	V_{DS} = 25 V, V_{GS} = 0 V, f = 1.0 MHz	--	6100	7900	pF
C_{oss}	Output Capacitance		--	2000	2600	pF
C_{rss}	Reverse Transfer Capacitance		--	420	550	pF
Switching Characteristics						
$t_{d(on)}$	Turn-On Delay Time	V_{DD} = 40 V, I_D = 140 A, R_G = 25 Ω	--	75	160	ns
t_r	Turn-On Rise Time		--	940	1890	ns
$t_{d(off)}$	Turn-Off Delay Time		--	350	710	ns
t_f	Turn-Off Fall Time	(Note 4)	--	360	730	ns
Q_g	Total Gate Charge	V_{DS} = 64 V, I_D = 140 A, V_{GS} = 10 V	--	220	285	nC
Q_{gs}	Gate-Source Charge		--	39	--	nC
Q_{gd}	Gate-Drain Charge	(Note 4)	--	114	--	nC
Drain-Source Diode Characteristics and Maximum Ratings						
I_S	Maximum Continuous Drain-Source Diode Forward Current	(Note 5)	--	--	140	A
I_{SM}	Maximum Pulsed Drain-Source Diode Forward Current		--	--	560	A
V_{SD}	Drain-Source Diode Forward Voltage	V_{GS} = 0 V, I_S = 140 A	--	--	1.5	V
t_{rr}	Reverse Recovery Time	V_{GS} = 0 V, I_S = 140 A, dI_F / dt = 100 A/μs	--	140	--	ns
Q_{rr}	Reverse Recovery Charge		--	730	--	nC

Notes:
1. Repetitive rating : pulse-width limited by maximum junction temperature.
2. L = 0.115 mH, I_{AS} = 140 A, V_{DD} = 25 V, R_G = 25 Ω, starting T_J = 25°C.
3. I_{SD} ≤ 140 A, di/dt ≤ 300 A/μs, V_{DD} ≤ BV_{DSS}, starting T_J = 25°C.
4. Essentially independent of operating temperature.
5. Continuous drain current calculated by maximum junction temperature : limited by package.
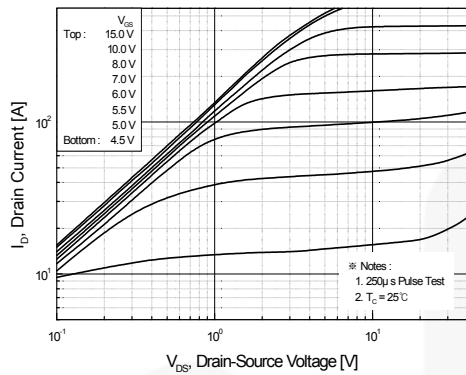
Typical Characteristics
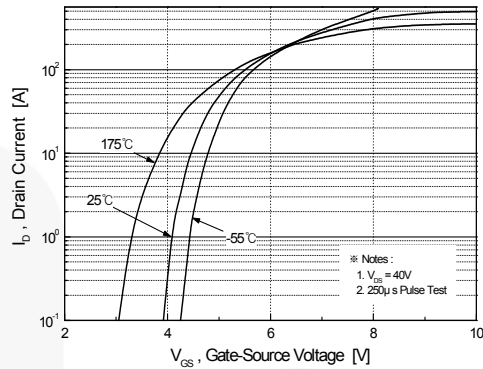

Figure 1. On-Region Characteristics

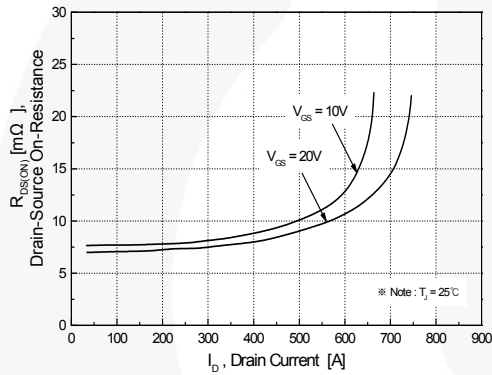Figure 2. Transfer Characteristics

Figure 3. On-Resistance Variation vs.
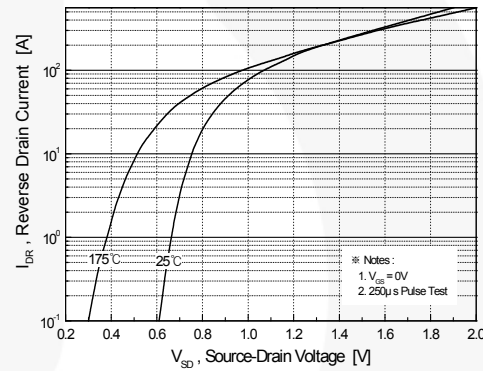Drain Current and Gate Voltage

Figure 4. Body Diode Forward Voltage
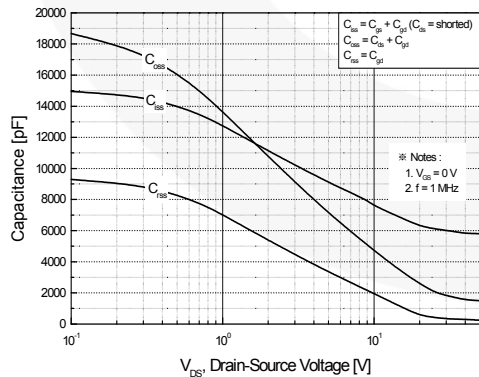Variation vs. Source Current
and Temperature
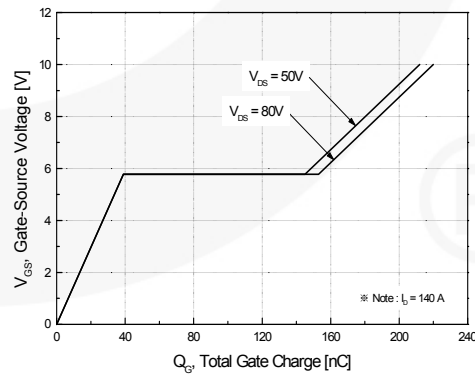

Figure 5. Capacitance Characteristics

Figure 6. Gate Charge Characteristics

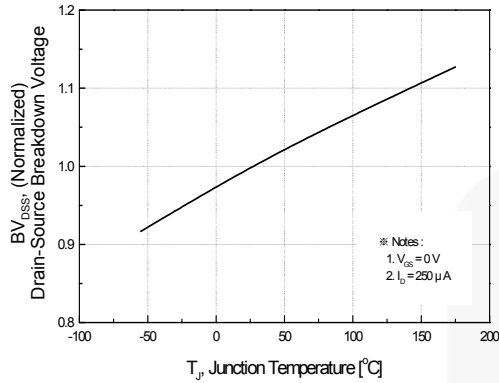## Typical Characteristics (Continued)

Figure 7. Breakdown Voltage Variation
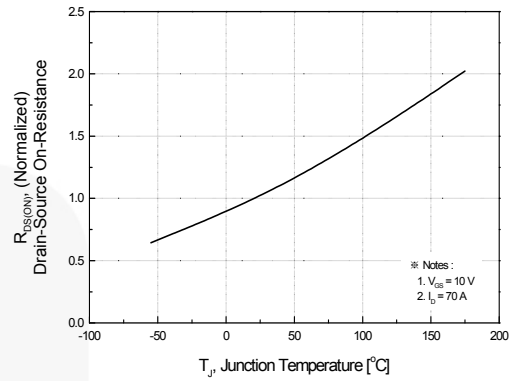vs. Temperature

Figure 8. On-Resistance Variation
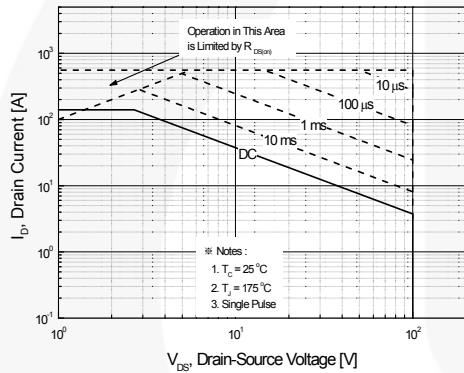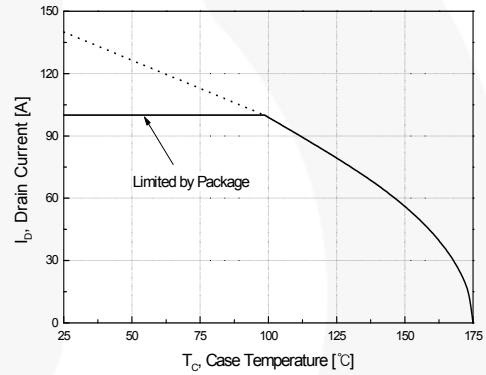vs. Temperature

Figure 9. Maximum Safe Operating Area
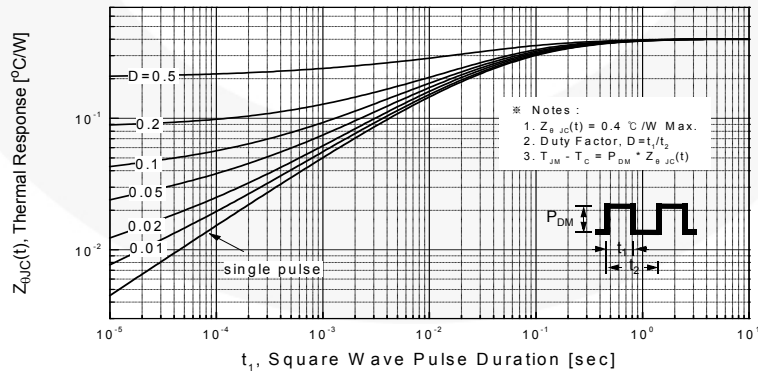

Figure 10. Maximum Drain Current
vs. Case Temperature

Figure 11. Transient Thermal Response Curve

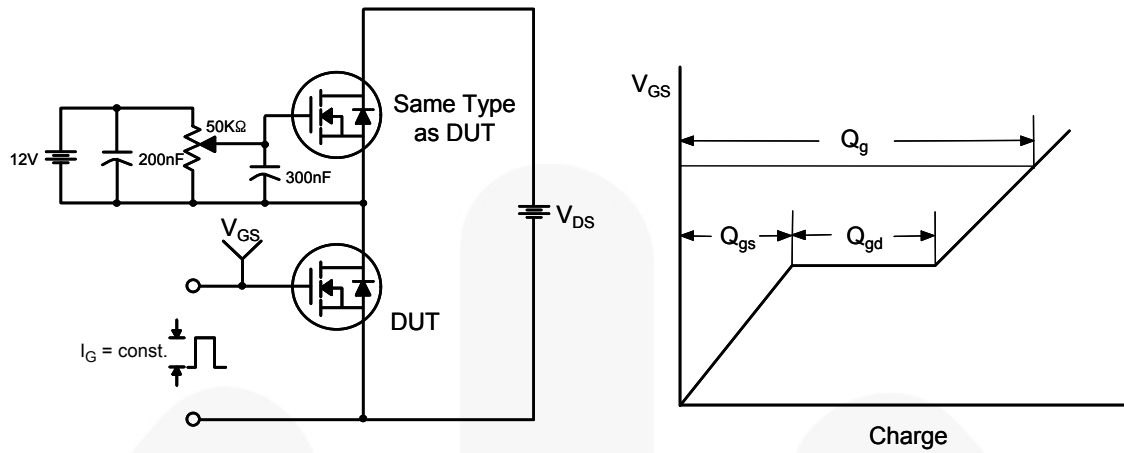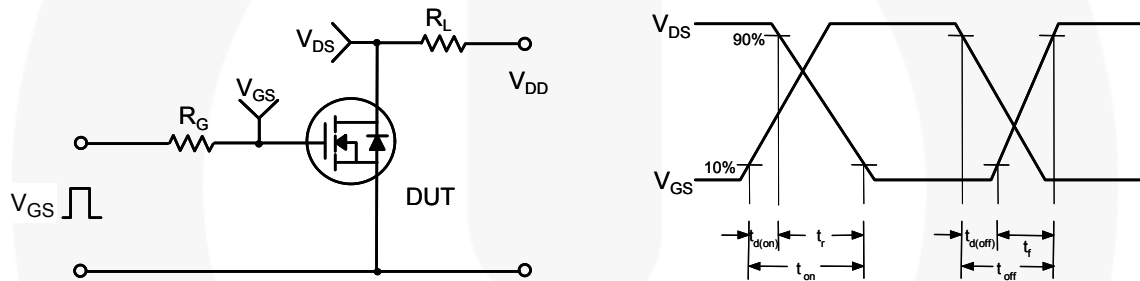**Figure 12. Gate Charge Test Circuit & Waveform**

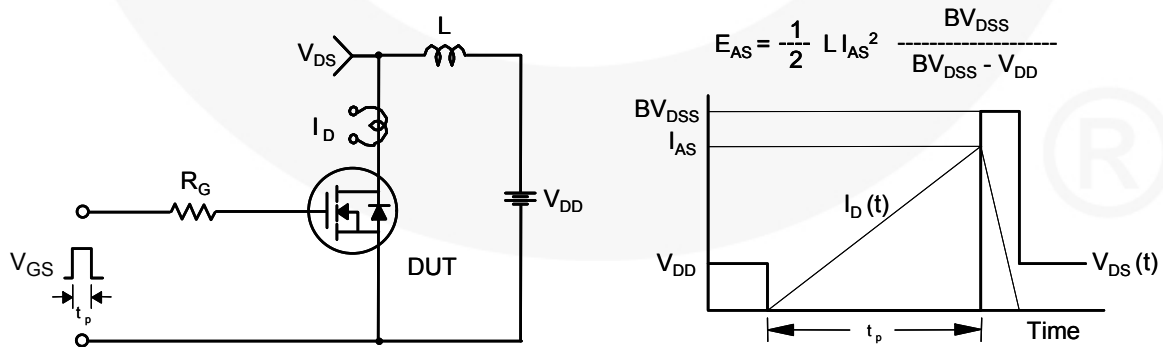**Figure 13. Resistive Switching Test Circuit & Waveforms**

$$E_{AS} = \frac{1}{2} \, L \, I_{AS}^2 \quad \frac{BV_{DSS}}{BV_{DSS} - V_{DD}}$$

Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms

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Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms

Mechanical Dimensions

Figure 16. TO3PN, 3-Lead, Plastic, EIAJ SC-65

NOTES: UNLESS OTHERWISE SPECIFIED

A) THIS PACKAGE CONFORMS TO EIAJ
   SC-65 PACKAGING STANDARD.
B) ALL DIMENSIONS ARE IN MILLIMETERS.
C) DIMENSION AND TOLERANCING PER
   ASME14.5-2009.
D) DIMENSIONS ARE EXCLUSSIVE OF BURRS,
   MOLD FLASH, AND TIE BAR EXTRUSSIONS.
E) DRAWING FILE NAME: TO3PN03AREV1.
F) FAIRCHILD SEMICONDUCTOR.

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